

MiniSKiiP[®] 2

3-phase bridge rectifier + brake chopper

SKiiP 28AHB16V1

Features

- Fast Trench IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

Typical Applications*

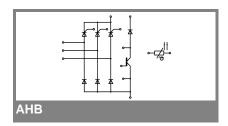
Input bridge for inverter up to 39 kVA

Remarks

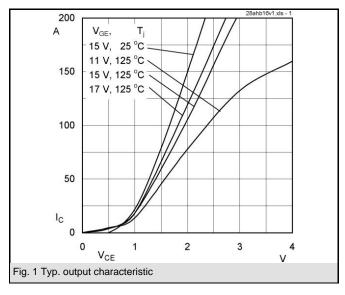
• V_{CEsat} , V_F = chip level value

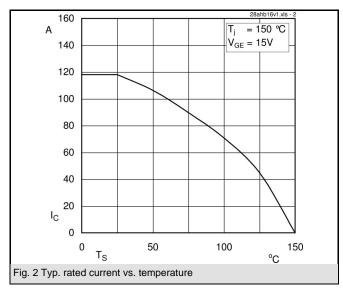
Absolute Maximum Ratings T _s = 25 °C, unless otherwise specified								
Symbol	Conditions	Values						
IGBT - Chopper								
V_{CES}		1200	V					
I _C	T _s = 25 (70) °C	118 (88)	Α					
I _{CRM}	$t_p \le 1 \text{ ms}$	210	Α					
V_{GES}		± 20	V					
T _j		- 40 + 150	°C					
Diode - Chopper								
I _F	T _s = 25 (70) °C	118 (88)	Α					
I _{FRM}	$t_p \le 1 \text{ ms}$	210	Α					
T _j		- 40 + 150	°C					
Diode / Thyristor - Rectifier								
V_{RRM}		1600	V					
I _F / I _T	T _s = 70	82	Α					
I _{FSM} / I _{TSM}	$t_p = 10 \text{ ms, sin } 180 ^\circ, T_i = 25 ^\circ\text{C}$	1000	Α					
i²t	$t_p = 10 \text{ ms, sin } 180 ^\circ, T_i = 25 ^\circ\text{C}$	5500	A²s					
T _i	Diode	- 40 + 150	°C					
T _j	Thyristor	- 40 + 125	°C					
I _{tRMS}	per power terminal (20 A / spring)	120	Α					
T _{stg}	$T_{op} \le T_{stg}$	- 40 + 125	°C					
V_{isol}	AC, 1 min.	2500	V					

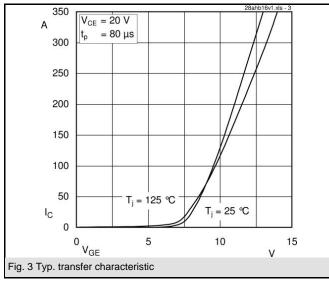
Characteristics		$T_s = 25 ^{\circ}C_s$	T _s = 25 °C, unless otherwise specified					
Symbol	Conditions	min.	typ.	max.	Units			
IGBT - Chopper								
V_{CEsat}	I _{Cnom} = 105 A, T _j = 25 (125) °C		1,7 (2)	2,1 (2,4)	V			
$V_{GE(th)}$	$V_{GE} = V_{CE}$, $I_C = 3 \text{ mA}$	5	5,8	6,5	V			
$V_{CE(TO)}$	T _j = 25 (125) °C		1 (0,9)		V			
r _T	$T_j = 25 (125) ^{\circ}C$		6,7 (10)	8,6 (12)	mΩ			
C _{ies}	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		8,4		nF			
Coes	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		1,5		nF			
C _{res}	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		1,1		nF			
$R_{th(j-s)}$	per IGBT		0,4		K/W			
t _{d(on)}	under following conditions		65		ns			
t _r	$V_{CC} = 600 \text{ V}, V_{GE} = \pm 15 \text{ V}$		30		ns			
$t_{d(off)}$	I _{Cnom} = 105 A, T _j = 125 °C		410		ns			
t _f	$R_{Gon} = R_{Goff} = 5.5 \Omega$		100		ns			
E _{on}	inductive load		14,4		mJ			
E_{off}			13,3		mJ			
Diode - C	Diode - Chopper							
$V_F = V_{EC}$	I _{Fnom} = 105 A, T _i = 25 (125) °C		1,6 (1,6)	1,8 (1,8)	V			
$V_{(TO)}$	T _j = 25 (125) °C		1 (0,8)	1,1 (0,9)	V			
r _T	$T_{j} = 25 (125) ^{\circ}C$		5,7 (7,6)	6,7 (8,6)	mΩ			
$R_{th(j-s)}$	per diode		0,55		K/W			
I _{RRM}	under following conditions		160		Α			
Q_{rr}	I _{Fnom} = 105 A, V _R = 600 V		26		μC			
E _{rr}	$V_{GE} = 0 \text{ V}, T_j = 125 ^{\circ}\text{C}$		10,8		mJ			
	di _F /dt = 5400 A/μs							

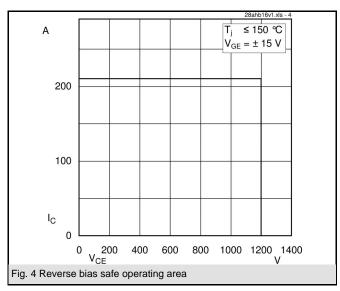


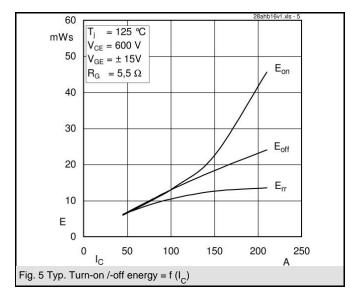
Characteristics		T _s = 25 °C, ur	T _s = 25 °C, unless otherwise specified					
Symbol	Conditions	min.	typ.	max.	Units			
Diode - Re	ectifier							
V_{F}	I _{Fnom} = 75 A, T _j = 25 °C		1,2		V			
V _(TO)	T _j = 150 °C		0,8		V			
r _T	T _j = 150 °C		7		mΩ			
$R_{th(j-s)}$	per diode		0,7		K/W			
Thyristor - Rectifier								
V _T	I _{Fnom} = 120 A, T _j = 25 (125) °C			1,8 (1,7)	V			
$V_{T(TO)}$	T _i = 125 °C			1,1	V			
r _T	T _j = 125 °C			5	mΩ			
V_{GT}	T _j = 25 °C			3	V			
I _{GT}	T _j = 25 °C	150			mA			
I _H	T _j = 25 °C		200		mA			
IL	T _j = 25 °C		400		mA			
dv/dt _(cr)	T _j = 125 °C			1000	V/µs			
di/dt _(cr)	T _j = 125 °C			50	A/µs			
$R_{th(j-s)}$	per thyristor		0,65		K/W			
Temperature Sensor								
R _{ts}	3 %, T _r = 25 (100) °C	10	00(1670)		Ω			
Mechanical Data								
w			65		g			
M _s	Mounting torque	2		2,5	Nm			

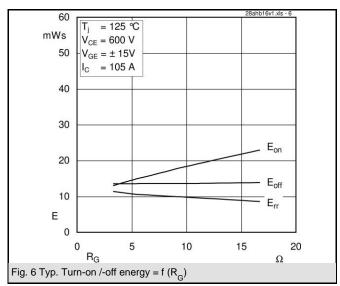


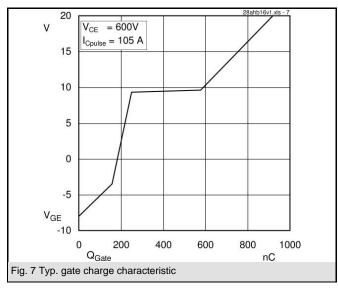


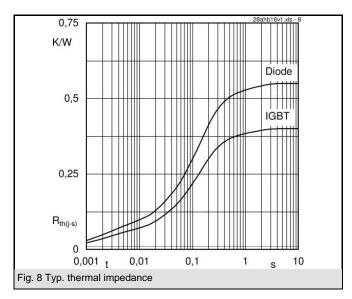


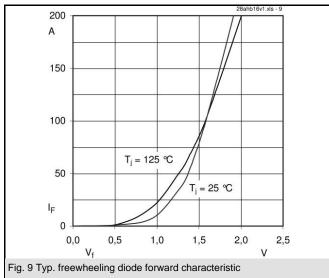


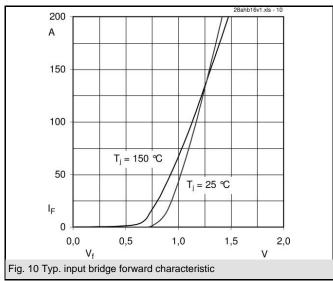


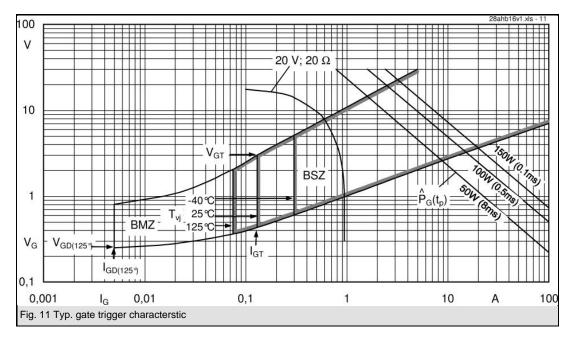


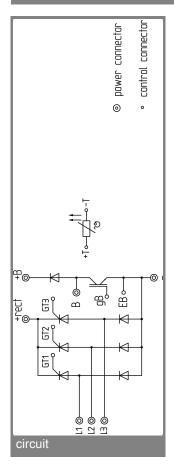


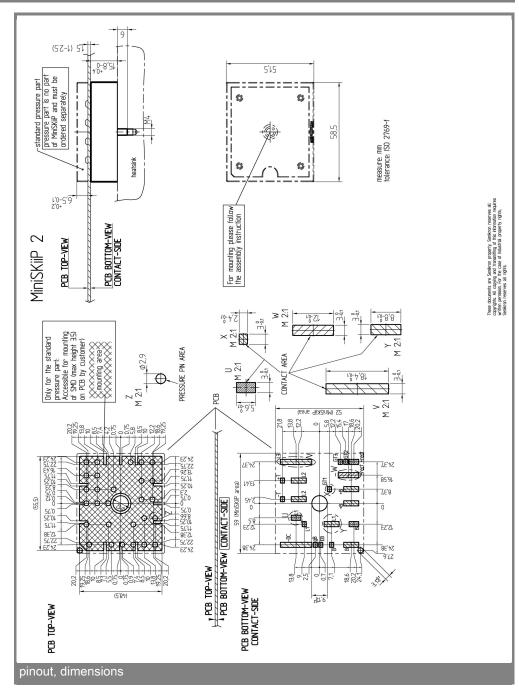












This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

^{*} The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.